

**Features:**

- Isolated mounting base 3000V~
  - Solder joint technology with increased power cycling capability
  - Space and weight saving
- Typical Applications:**
- AC/DC Motor drives
  - Various rectifiers
  - DC supply for PWM inverter

V <sub>DRM</sub> , V <sub>RRM</sub>	Type & Outline		
	600V	800V	1000V
1200V	DSKT55/12E-224H3/224H3B		
1400V	DSKT55/14E-224H3/224H3B		
1600V	DSKT55/16E-224H3/224H3B		
1800V	DSKT55/18E-224H3/224H3B		

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>J</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>T(AV)</sub>	Mean on-state current	180° half sine wave 50Hz Single side cooled, T <sub>c</sub> =85°C	125			55	A
I <sub>T(RMS)</sub>	RMS on-state current		125			86	A
I <sub>DRM</sub> I <sub>RRM</sub>	Repetitive peak current	at V <sub>DRM</sub> at V <sub>RRM</sub>	125			15	mA
I <sub>TSM</sub>	Surge on-state current	10ms half sine wave V <sub>R</sub> =60%V <sub>RRM</sub>	125			1.7	kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination					14.5	10 <sup>3</sup> A <sup>2</sup> s
V <sub>TO</sub>	Threshold voltage		125			0.75	V
r <sub>T</sub>	On-state slope resistance					4.05	mΩ
V <sub>TM</sub>	Peak on-state voltage	I <sub>TM</sub> =170A	25			1.60	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> =67%V <sub>DRM</sub>	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	Gate source 1.5A t <sub>r</sub> ≤0.5μs Repetitive	125			200	A/μs
I <sub>GT</sub>	Gate trigger current	VA=12V, I <sub>A</sub> =1A	25	30		200	mA
V <sub>GT</sub>	Gate trigger voltage			0.6		2.5	V
I <sub>H</sub>	Holding current			10		250	mA
I <sub>L</sub>	Latching current					1000	mA
V <sub>GD</sub>	Non-trigger gate voltage	V <sub>DM</sub> =67%V <sub>DRM</sub>	125			0.2	V
R <sub>th(j-c)</sub>	Thermal resistance Junction to case	Single side cooled, per chip				0.47	°C/W
R <sub>th(c-h)</sub>	Thermal resistance case to heatsink	Single side cooled, per chip				0.15	°C/W
V <sub>iso</sub>	Isolation voltage	50Hz,R.M.S,t=1min,I <sub>iso</sub> :1mA(MAX)		3000			V
F <sub>m</sub>	Thermal connection torque(M5)			2.5		4.0	N·m
	Mounting torque(M6)			4.5		6.0	N·m
T <sub>vj</sub>	Junction temperature			-40		125	°C
T <sub>stg</sub>	Stored temperature			-40		125	°C
W <sub>t</sub>	Weight				100		g
Outline		224H3、224H3B					

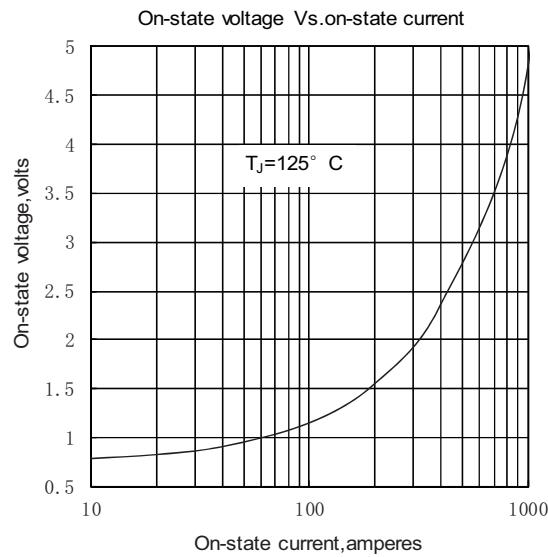


Fig.1

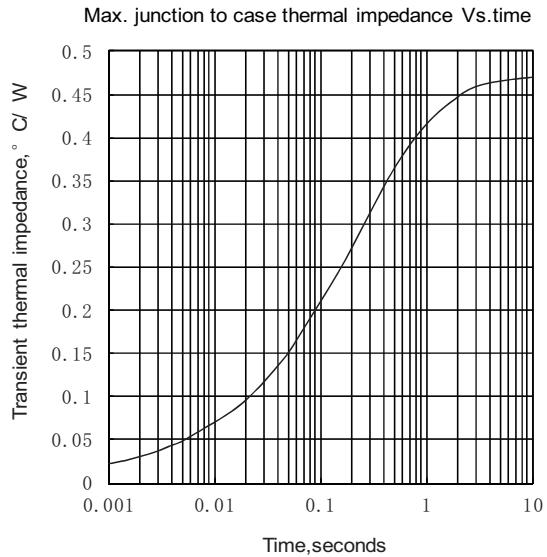


Fig.2

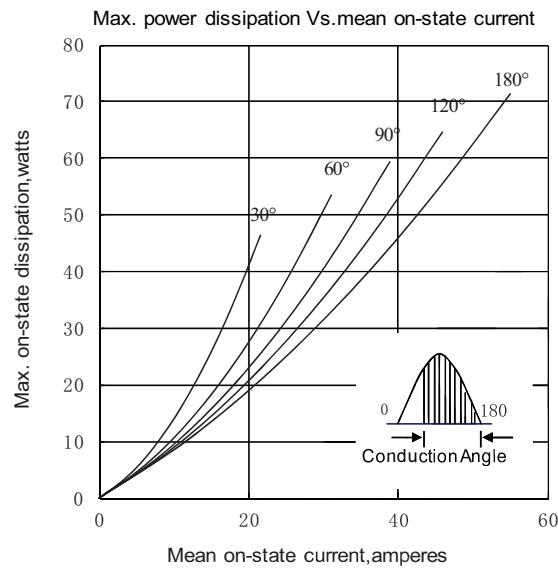


Fig.3

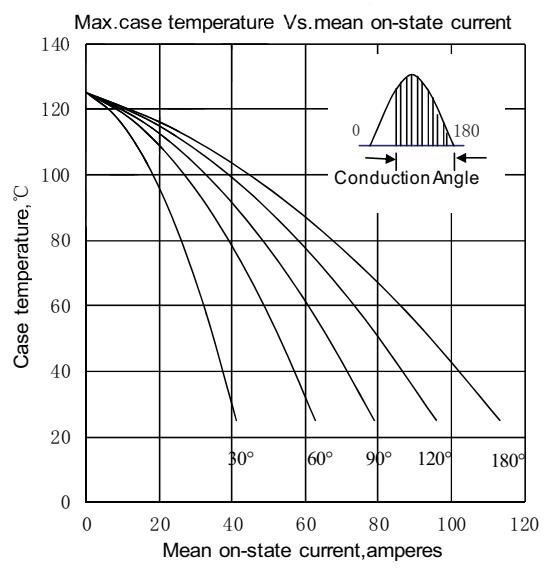


Fig.4

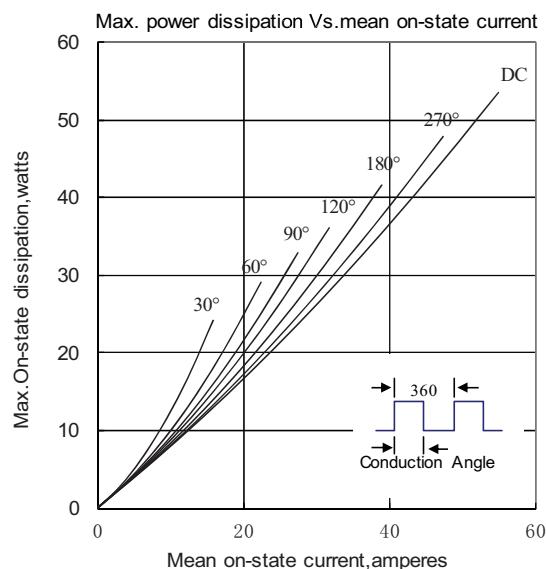


Fig.5

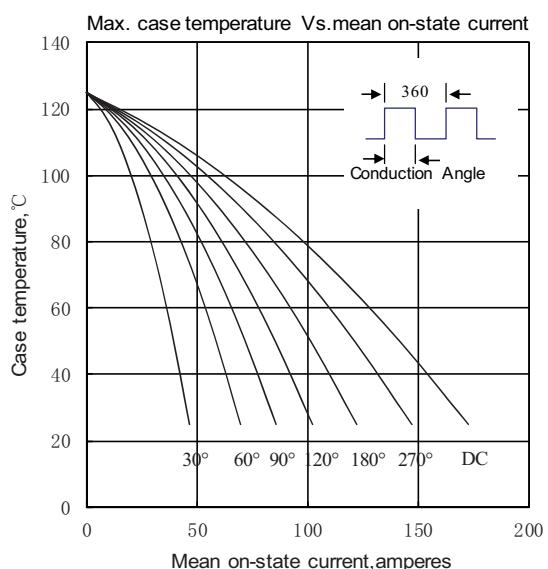


Fig.6

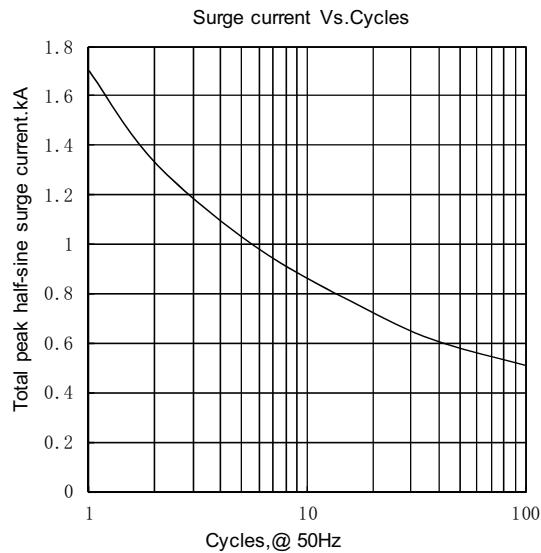


Fig.7

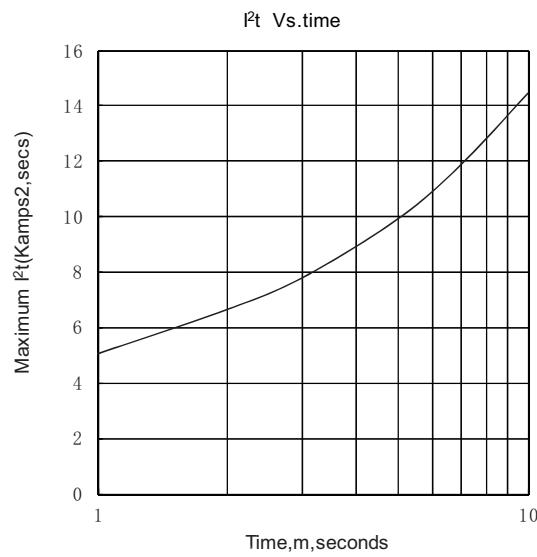


Fig.8

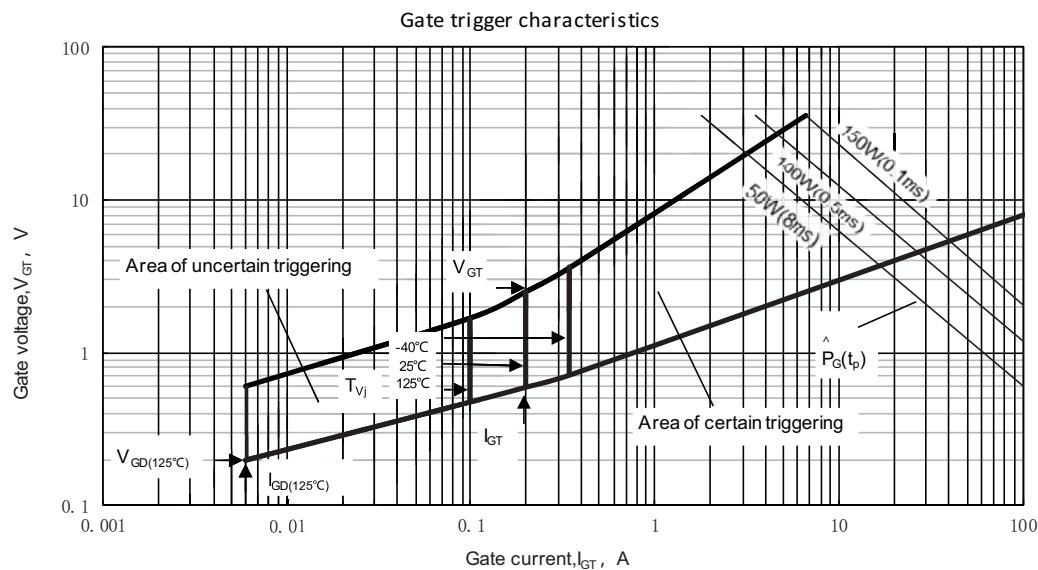
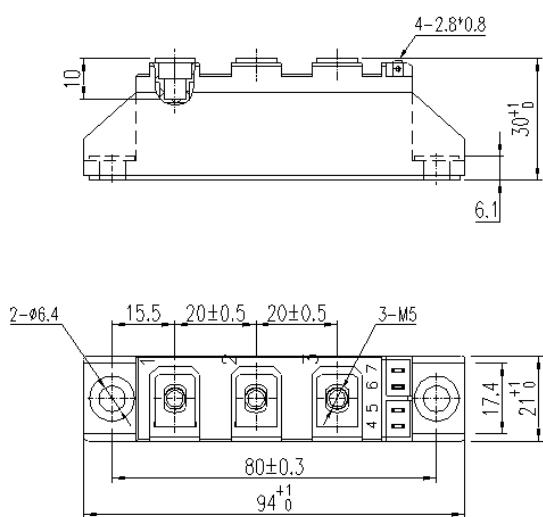
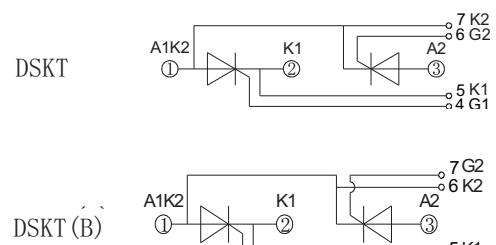


Fig.9

**Outline:**

Unmarked dimensional tolerance: ±0.5mm

3/3



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